



NEC's NPN SILICON TRANSISTOR

NE681M13

FEATURES

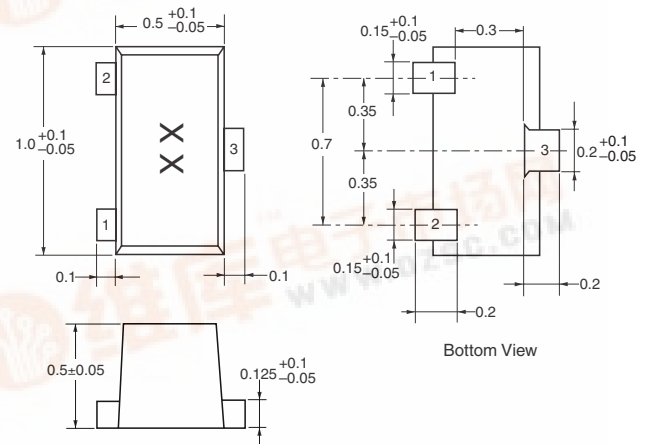
- **NEW MINIATURE M13 PACKAGE:**
 - Small transistor outline – 1.0 X 0.5 X 0.5 mm
 - Low profile / 0.50 mm package height
 - Flat lead style for better RF performance
- **HIGH GAIN BANDWIDTH PRODUCT:**
 $f_T = 7 \text{ GHz}$
- **LOW NOISE FIGURE:**
 $NF = 1.4 \text{ dB}$

DESCRIPTION

NEC's NE681M13 transistor is ideal for low noise, high gain, and low cost amplifier applications. NEC's new low profile/flat lead style "M13" package is ideal for today's portable wireless applications. The NE681 is also available in chip, Micro-x, and six different low cost plastic surface mount package styles.

OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE M13



PIN CONNECTIONS

1. Emitter
2. Base
3. Collector

ELECTRICAL CHARACTERISTICS (TA = 25°C)

PART NUMBER EIAJ ¹ REGISTERED NUMBER PACKAGE OUTLINE		NE681M13 2SC5615 M13			
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
f_T	Gain Bandwidth at $V_{CE} = 3 \text{ V}$, $I_C = 7 \text{ mA}$, $f = 1 \text{ GHz}$	GHz	4.5	7	
NF	Noise Figure at $V_{CE} = 3 \text{ V}$, $I_C = 7 \text{ mA}$, $f = 1 \text{ GHz}$	dB		1.4	2.7
$IS_{21E}I^2$	Insertion Power Gain at $V_{CE} = 3 \text{ V}$, $I_C = 7 \text{ mA}$, $f = 1 \text{ GHz}$	dB	10	12	
h_{FE}^2	Forward Current Gain at $V_{CE} = 3 \text{ V}$, $I_C = 7 \text{ mA}$		80		145
I_{CBO}	Collector Cutoff Current at $V_{CB} = 10 \text{ V}$, $I_E = 0$	μA			0.8
I_{EBO}	Emitter Cutoff Current at $V_{EB} = 1 \text{ V}$, $I_C = 0$	μA			0.8
C_{RE}^3	Feedback Capacitance at $V_{CB} = 3 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$	pF			0.9

Notes:

1. Electronic Industrial Association of Japan.
2. Pulsed measurement, pulse width $\leq 350 \mu\text{s}$, duty cycle $\leq 2\%$.
3. Capacitance is measured with emitter and case connected to the guard terminal at the bridge.



NE681M13

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V _{CB0}	Collector to Base Voltage	V	20
V _{CEO}	Collector to Emitter Voltage	V	10
V _{EBO}	Emitter to Base Voltage	V	1.5
I _C	Collector Current	mA	65
P _T ²	Total Power Dissipation	mW	140
T _J	Junction Temperature	°C	150
T _{STG}	Storage Temperature	°C	-65 to +150

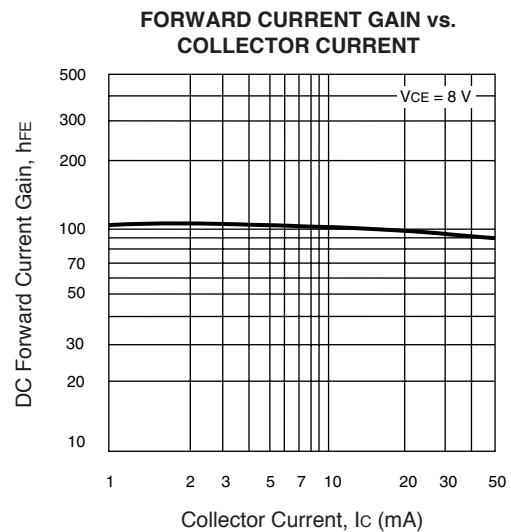
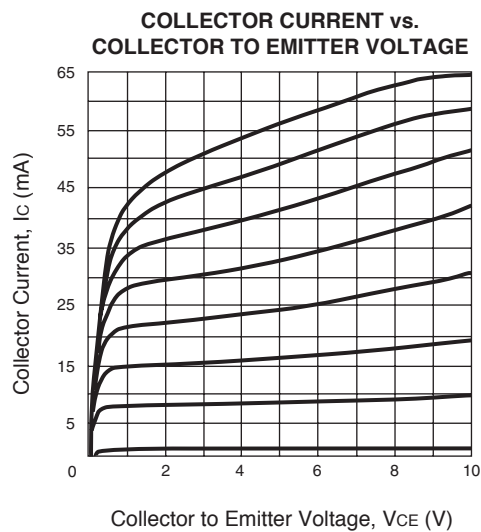
Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. With device mounted on 1.08 cm² X 1.2 mm glass epoxy board.

ORDERING INFORMATION

PART NUMBER	QUANTITY
NE681M13-A	
NE681M13-T3-A	

TYPICAL PERFORMANCE CURVES (T_A = 25°C)



Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL’s understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
		-A	-AZ
Lead (Pb)	< 1000 PPM	Not Detected	(*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

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